

IN THE SPECIFICATION:

Page 3, lines 31-33:

This galenical form and the process for its manufacture have been described in ~~international published US~~ patent application ~~WO 01/62256 2003/0045522~~, which is incorporated here by ~~way of~~ reference.

Page 4, lines 17-19:

Within the framework of the present invention, any galenical form as described in said ~~international published US~~ patent application ~~WO 01/62256 2003/0045522~~ can advantageously be used.